# ChemComm

# Accepted Manuscript



This is an *Accepted Manuscript*, which has been through the Royal Society of Chemistry peer review process and has been accepted for publication.

Accepted Manuscripts are published online shortly after acceptance, before technical editing, formatting and proof reading. Using this free service, authors can make their results available to the community, in citable form, before we publish the edited article. We will replace this Accepted Manuscript with the edited and formatted Advance Article as soon as it is available.

You can find more information about *Accepted Manuscripts* in the **Information for Authors**.

Please note that technical editing may introduce minor changes to the text and/or graphics, which may alter content. The journal's standard <u>Terms & Conditions</u> and the <u>Ethical guidelines</u> still apply. In no event shall the Royal Society of Chemistry be held responsible for any errors or omissions in this *Accepted Manuscript* or any consequences arising from the use of any information it contains.



www.rsc.org/chemcomm

Cite this: DOI: 10.1039/c0xx00000x

www.rsc.org/xxxxxx

# **ARTICLE TYPE**

# ChemComm Accepted Manuscript

## Electrochemical "Read-Write" Microscale Patterning of Boron Doped Diamond Electrodes

Hollie V. Patten, <sup>a‡</sup> Laura A. Hutton, <sup>a‡</sup> Jennifer R. Webb, <sup>a,b</sup> Mark E. Newton, <sup>c</sup> Patrick R. Unwin<sup>a</sup>\* and Julie V. Macpherson<sup>a</sup>\*

s Received (in XXX, XXX) Xth XXXXXXX 20XX, Accepted Xth XXXXXXXX 20XX DOI: 10.1039/b000000x

Scanning electrochemical cell microscopy is utilised as a readwrite pipette-based probe to both electrochemically modify the local surface chemistry of boron doped diamond and

- <sup>10</sup> "read" the resulting modification, at the micron scale. In this specific application, localised electrochemical oxidation results in conversion of the H-terminated surface to -O, electrochemically visualised by monitoring the current change for reduction of Ru(NH<sub>3</sub>)<sub>6</sub><sup>3+</sup>. This methodology, in
- <sup>15</sup> general, provides a platform for read-write analysis of electrodes, opening up new analysis avenues, particularly as the pipette can be viewed as a microfluidic device.

Controlling the surface chemistry of electrodes is of great importance for the fabrication of sensors in order to improve

- <sup>20</sup> electrocatalytic performance and enable an assessment of the impact of surface chemistry on the fundamentals of electrochemical phenomena.<sup>1</sup> Patterning of an electrode can lead to higher detection sensitivities, the ability to both sense multiple analytes and make many measurements on one device. Various
- <sup>25</sup> approaches to patterning have been proposed, the most popular being lithography, where a mask is used to define regions of the surface for subsequent chemical modification. For conventional metal electrodes, self-assembled monolayers, or physisorbed molecules are typically attached to the localised region of interest
- <sup>30</sup> in order to tailor the molecular surface chemistry.<sup>2</sup> However, this is a write-only process and other techniques must then be utilised to "read" the resulting chemical functionalization.

In the electrochemistry field, conducting boron doped diamond (BDD) electrodes are proving popular due to their

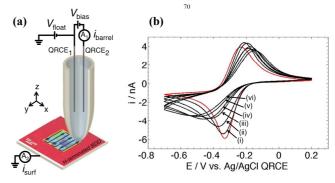
- <sup>35</sup> biocompatibility, larger solvent windows (compared to a metal electrode), low background currents and processability. Chemical functionalisation of BDD is particularly attractive due to the considerable stability of the surface chemical bonds.<sup>3</sup> At the simplest level, diamond can be either –H or –O terminated.
- <sup>40</sup> For example, diamond materials grown under a hydrogen atmosphere are H-terminated, rendering the surface hydrophobic. Alternatively, oxygen (-O) termination is possible using a variety of methods including, for example, boiling in acid, exposure to an O<sub>2</sub> plasma or anodic polarisation.<sup>4</sup> O-terminated surfaces are
- <sup>45</sup> hydrophilic. Other methods also exist for terminating the surface with a wide variety of more complex molecular species.<sup>3</sup> On insulating diamond, H-termination results in a measurable surface

conductivity, due to surface transfer doping and an increase in available charge carriers.<sup>5</sup> Hence, for diamond, changing surface <sup>50</sup> termination not only influences the surface chemistry but can also affect the electrical characteristics. We exploit this phenomenon

affect the electrical characteristics. We exploit this phenomenon for the read-write technology described herein.

The amount of boron doping in diamond controls the electrical properties. For metal-like behaviour, the diamond must be doped

- ss with  $> 10^{20}$  B atoms cm<sup>-3,6</sup> Boron levels less than this result in ptype semi-conducting behaviour. Microscale chemical patterning of diamond surfaces has been achieved using several techniques including lithographic chemical/molecular functionalization,<sup>7</sup> and scanning probe modification.<sup>8,9,10</sup> In the latter, an anodically
- <sup>60</sup> biased tip was used to (electro)chemically pattern regions of either a bare (H-terminated) surface<sup>8,9</sup> or one which had been chemically modified,<sup>10</sup> in air. The tip was also used to image the resulting modification by either recording the change in surface topography<sup>10</sup> or local conductivity.<sup>9</sup>
- <sup>65</sup> In this communication we present a new electrochemical approach to the microscale "read-write" chemical patterning of diamond electrodes using scanning electrochemical cell microscopy (SECCM), as illustrated in Figure 1a.<sup>11,12</sup>



**Figure 1**: (a) Illustration of the SECCM set-up, showing the use of a theta capillary of ~  $\mu$ m diameter to both locally modify the surface (write) and then subsequently read the resulting surface change. (b) Successive CVs recorded at 0.1 V s<sup>-1</sup> after [×5], 1 s anodic pulses at +1.5 V, recorded <sup>75</sup> successively for a total of 30 pulses, for the reduction of 1 mM Ru(NH<sub>3</sub>)<sub>6</sub><sup>3+</sup> in 0.1 M KNO<sub>3</sub> on H-terminated semiconducting BDD, using a microcapillary of diameter ~ 52 µm.

90

SECCM employs a scanning dual channel (theta) pipette, filled with the electrolyte solution of interest and a quasi-reference counter electrode (QRCE) in each channel. This constitutes a conductimetric cell. A further dynamic electrochemical cell is

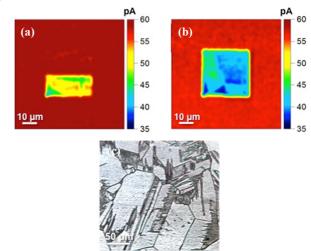
s created when the meniscus protruding from the end of the pipet makes contact with the (working) electrode substrate, biased at a potential, with respect to the QRCEs, to drive an electrochemical process of interest.

In this application the SECCM tip is used to both spatially

- <sup>10</sup> convert the electrode surface from -H to O-termination using anodic polarisation (write) and image the resulting change in surface termination using an electrochemical approach (read), at the micron scale. Here we employ semi-conducting BDD in conjunction with the outer sphere redox mediator  $Ru(NH_3)_6^{3+}$ ; the
- <sup>15</sup> reduction potential of which lies in the band gap of semiconducting p-type BDD.<sup>13</sup> Alternatively, conducting BDD could be utilised in partnership with inner sphere redox probes. Experiments initially explored the effect of applied anodic potential on the electrochemical response of freestanding H-
- $_{20}$  terminated semi-conducting polycrystalline BDD (2  $\times$  10<sup>18</sup> boron atoms cm<sup>-3</sup>; grain size  $\sim$  7 100  $\mu$ m,<sup>13</sup> grown by Element Six, Harwell, UK) using a larger scale microcapillary technique.<sup>14</sup> The BDD surface was polished to an  $\sim$  nm finish using a diamond lapping technique.<sup>13</sup> Briefly, the set-up employed a glass
- <sup>25</sup> borosilicate capillary pulled and polished to an inner diameter of  $\sim$ 52 µm, filled with the solution of interest (defined below) and containing an Ag/AgCl (AgCl-coated Ag wire) QRCE. The meniscus from the tip was positioned on a localised region of the surface using *x-y-z* micropositioners, aided by visualisation from <sup>30</sup> a high magnification camera (Pixelink PL-B776U).
- Figure 1b shows cyclic voltammograms (CVs) recorded at a scan rate of 0.1 V s<sup>-1</sup> for reduction of Ru(NH<sub>3</sub>)<sub>6</sub><sup>3+</sup> (1 mM) in 0.1 M KNO<sub>3</sub> on a H-terminated semiconducting BDD electrode,<sup>13, 15</sup> functionalised before use with a hydrogen plasma,<sup>13</sup> and
- <sup>35</sup> confirmed to be hydrophobic by contact angle analysis.<sup>16</sup> A typical initial CV, shown in Figure 1 (red), with a start and end potential of 0.2 V, and a reverse potential of -0.7 V, was recorded on the freshly H-terminated surface. With the capillary held in the same position, the electrode was then subject to anodic
- <sup>40</sup> polarisation at +1.5 V vs. Ag/AgCl QRCE for 1 s, followed by a wait period of 5 s at the start potential and a CV was recorded again. This procedure was repeated 30 times. The resulting CVs are shown in Figure 1 after (i) 5; (ii) 10; (iii) 15; (iv) 20; (v) 25 and (vi) 30, 1 s pulses.
- <sup>45</sup> On O-terminated semi-conducting BDD, electron transfer (ET) has been shown to be sluggish for Ru(NH<sub>3</sub>)<sub>6</sub><sup>3+/2+,13</sup> However, as shown here, surface transfer doping, due to H-termination<sup>17</sup> results in a peak to peak separation,  $\Delta E_p$ , for the redox couple Ru(NH<sub>3</sub>)<sub>6</sub><sup>3+/2+</sup> of ~ 96 mV, indicative of significantly faster ET
- <sup>50</sup> kinetics than would be expected for the O-terminated surface. Notably, after just 1 s of anodic treatment, on the freshly Hterminated surface,  $\Delta E_p$  is observed to increase to 116 mV. It is well documented that anodic polarisation of the BDD surface leads to a change in surface termination;<sup>4c,13</sup> the relative
- <sup>55</sup> contributions of different -O groups formed on the surface dependent on the polycrystallinity of the material and the extent of the treatment. As shown in Figure 1, repeated anodic polarisation leads to a significant increase in  $\Delta E_p$  due to the

removal of local charge carriers as the surface termination <sup>60</sup> changes from -H to -O. After 30 s of anodic treatment  $\Delta E_p$  is ~ 378 mV.<sup>16</sup> Note that such effects would be unlikely if the material was doped to be metal-like as the number of available charge carriers would be sufficiently high to ensure fast ET irrespective of surface termination.<sup>13</sup> For example, H- and O-terminated <sup>65</sup> metallic doped BDD macrodisc electrodes show very similar CV responses towards the reduction of Ru(NH<sub>3</sub>)6<sup>3+,13</sup>

The premise that the local BDD surface termination could be both modified (write) and detected electrochemically (read) was further investigated using SECCM (Figure 1a). In brief, a <sup>70</sup> borosilicate theta capillary of inner diameter of *ca*. 1-2  $\mu$ m, filled with solution (2 mM Ru(NH<sub>3</sub>) $_{6}^{3+}$  in 50 mM KNO<sub>3</sub>) was used as the read-write probe. A potential, V<sub>bias</sub> of 200 mV was applied between the QRCEs in each barrel. During approach to the surface, a small oscillation (60 nm) in the z-position of the probe 75 was applied. When the meniscus came into contact with the surface, an alternating current component,  $i_{AC}$ , in the current between the barrels was established; which was very sensitive to the tip-substrate separation. In SECCM,  $i_{AC}$  is used as a set point for electrochemical imaging, in this case to maintain contact 80 between the meniscus and diamond surface. For the studies herein, the  $i_{AC}$  values were in the range 80-120 pA, about 1 % of the mean conductance current,  $i_{\text{barrel}}$ , and about two orders of magnitude above the background (residual) value of  $i_{AC}$  when the probe was away from the surface The BDD electrode was 85 grounded and the effective potential controlled by floating the conductimetric cell at a potential,  $V_{\text{float}}$ , so that the potential of the diamond substrate was  $-(V_{\text{float}} + V_{\text{bias}}/2)$  with respect to the QRCE potential.18



**Figure 2:** (a) and (b) SECCM read-write scans of selected regions on Hterminated BDD, anodically oxidised by biasing at +1.5 V (write) and imaged (read) at -0.3 V using an SECCM probe of ~  $\mu$ m diameter, filled 100 with 2 mM Ru(NH<sub>3</sub>)<sub>6</sub><sup>3+</sup> in 50 mM KNO<sub>3</sub>. (c) Optical image of the grain structure of the polycrystalline BDD electrode employed.

In initial SECCM experiments, the SECCM probe was used to anodically oxidise a small area (10  $\mu$ m × 20  $\mu$ m) of the H-<sup>105</sup> terminated semiconducting electrode. For the first half of a 20  $\mu$ m × 20  $\mu$ m scan (scanning bottom to top) an effective anodic oxidation potential of +1.5 V was applied and then switched to -0.3 V for the remainder of the scan, which is only sufficient to reduce  $Ru(NH_3)_6^{3+}$  on the H-terminated surface (Figure 1b). To view the resulting surface modification, SECCM imaging was

- s carried out over a larger 50  $\mu$ m × 50  $\mu$ m scan area, with the area previously scanned in the centre. An effective potential of -0.3 V was applied to the electrode, and the electrochemical current recorded every 1  $\mu$ m (tip scan speed 1  $\mu$ m s<sup>-1</sup>) and plotted as an activity map, as shown in Figure 2a.
- <sup>10</sup> As seen in Figure 2a, anodic treatment results in a measurably smaller current for reduction of  $\text{Ru(NH)}_6^{3+}$  due to partial anodic removal of the H-termination layer, qualitatively consistent with the data in Figure 1. The residence time of the meniscus in the vicinity of the electrode surface was  $\sim 1 \text{ s}$  during local
- <sup>15</sup> modification (writing) and subsequent activity imaging (reading), and this is clearly sufficient to modify the surface termination. The current response in the top half of the scan stays relatively constant (58.9 ± 0.6 pA, n = 173 pixels) and is similar to that seen in the larger 50 µm × 50 µm scan area (58.1 ± 2.9 pA, n = 173
- <sup>20</sup> pixels). The similarities of the currents recorded in the Hterminated regions of the surface suggest that no significant change in termination was caused by either the physical act of scanning across the surface, or during application of the -0.3 V potential, during the 'write process.
- <sup>25</sup> Interestingly, the area of the activity scan modified by anodic polarisation displays a heterogeneously varying current, reminiscent of earlier work on metallic O-terminated polycrystalline BDD which showed that differently doped grains (facet) have different electroactivity.<sup>19,20</sup> In order to investigate
- <sup>30</sup> this further, a full 20  $\mu$ m × 20  $\mu$ m oxidising scan was performed in a new area of the sample, and then imaged at -0.3 V over 50  $\mu$ m × 50  $\mu$ m, to promote the reduction of Ru(NH)<sub>6</sub><sup>3+</sup>, using the same conditions as before (Figure 2b). The decreased activity current (read) magnitude in the region of the anodic (write)
- <sup>35</sup> pretreatment is again apparent, as are angular features demarking areas of different activity. These different zones most likely represent the different crystal facets associated with this polycrystalline material, as shown optically in Figure 2c, which contain differing amounts of boron, and which may also be
- <sup>40</sup> subject to different degrees of oxygen termination (or depletion of charge carriers), during the 'write' process. In summary, Figure 2b demonstrates that using SECCM it is possible to confine the electrochemical patterning process to ~ micron sized areas on the surface. It should also be possible to achieve even <sup>45</sup> higher spatial resolution in the future by employing smaller

imaging pipettes.<sup>21</sup> It is of interest to investigate the extent to which the electrochemical activity of the diamond surface can be tuned. A

- smaller scan area of 10  $\mu$ m × 10  $\mu$ m was electrochemically so oxidised by scanning the SECCM meniscus over the surface (bottom to top) a total of three times, with the surface biased at +1.5 V (1  $\mu$ m s<sup>-1</sup> scan speed). Imaging took place after each oxidative scan at an effective potential of -0.3 V, over a scan area of 20  $\mu$ m × 20  $\mu$ m to capture (read) the activity of the modified
- ss area and the immediate surrounding (unmodified) area. Figure 3 shows (i) the BDD electrochemical current response and (ii) the conductance current response between the two channels of the

theta pipette for the reduction of 2 mM  $\text{Ru(NH)}_{6}^{3+}$  after the (a) first; (b) second and (c) third oxidative (modification) scans.

<sup>60</sup> Figures 3ai to ci, show that there is a gradual decrease in Ru(NH<sub>3</sub>)<sub>6</sub><sup>3+</sup> reductive currents in the square region with consecutive scans, indicating the gradual removal of the H-termination layer with subsequent oxidative scans. After three scans the currents in the central region of the O-terminated area
<sup>65</sup> of the surface have dropped by over 90%, compared to the surrounding H-terminated regions. Figures 3aii – cii are further illuminating on the effect of surface termination. These show the dc conductance current between the QRCEs in the barrels of the theta pipette, highlighting that in the modified region this <sup>70</sup> increases by about 20% which can be attributed to a change in the meniscus contact<sup>18</sup> due to increased wetting of the surface in the O-terminated regions.

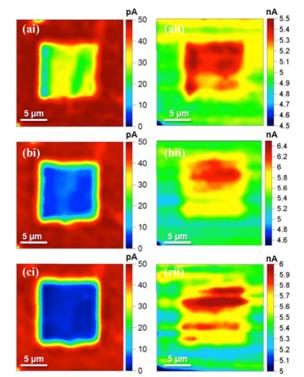


Figure 3: SECCM read-write (i) electrochemical current maps and (ii) tip 75 dc conductance maps recorded simultaneously, after three consecutive oxidative scans (a) to (c), recorded with (i) the BDD electrode biased at -0.3 V (read), after writing took place at +1.5 V and (ii) +200 mV applied between the two QRCEs in each barrel, in a theta capillary of ~  $\mu$ m diameter, filled with 2 mM Ru(NH<sub>3</sub>)<sub>6</sub><sup>3+</sup> and 50 mM KNO<sub>3</sub> on H-80 terminated BDD.

In summary, the studies herein show that SECCM can be used to alter the surface properties of a diamond electrode such that electrochemistry is inhibited in some regions, while being srelatively facile in others. This opens up the prospect of surface patterning and the creation on electrochemical (and electronic) devices by the local chemical modification of diamond. On a conducting BDD surface we envisage alternative inner sphere redox probes could be employed to read the modification process. 90 Furthermore, it has been successfully demonstrated that the 70

80

surface termination of diamond electrode can be both modified (write) and detected (read) using SECCM imaging, with a simple pipette. This also provides a platform for write-read analysis of other surfaces, opening up new avenues for analysis, particularly

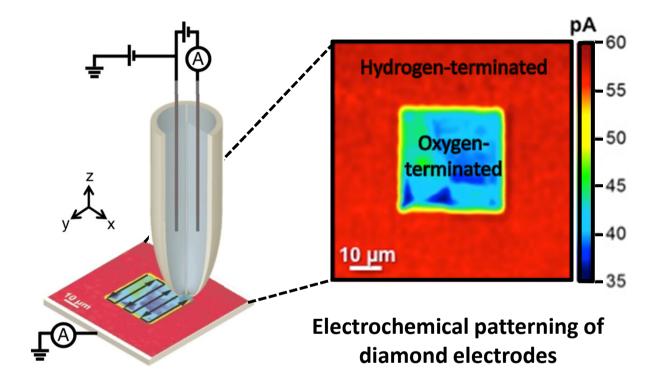
- <sup>5</sup> as the pipette can be viewed as a microfluidic device.<sup>22</sup> With further work, it may also be possible to effect write-read-erase strategies on conducting diamond in view of the possibility of creating H-terminated surfaces electrochemically.<sup>23</sup>
- <sup>10</sup> HVP and LAH would like to thank Element Six (E6: Harwell, UK) for funding and JRW thanks the EPSRC for a MOAC Doctoral Training Centre studentship. PRU acknowledges support from a European Research Council Advanced Investigator Grant (ERC-2009-AdG 247143; "QUANTIF"). We
- 15 all thank E6 for provision of the BDD electrodes. Equipment used in this research was obtained through Science City (AM2), with support from Advantage West Midlands.

### Notes and references

- <sup>a</sup> Department of Chemistry, University of Warwick, Coventry, CV4 7AL, 20 UK. Fax: +44(0)2476 524112; Tel: +44 (0)2476 573886; E-mail:
- j.macpherson@warwick.ac.uk; p.r.unwin@warwick.ac.uk <sup>b</sup> MOAC Doctoral Training Centre, University of Warwick, Coventry, CV4 7AL UK.
- <sup>c</sup> Department of Physics, University of Warwick, Coventry, CV4 7AL UK. 25 ‡ LAH and HVP contributed equally to this work
  - 1 M. Shen and A. J. Bard, *Journal of the American Chemical Society*, 2011, **133**, 15737.
- J. C. Love, L. A. Estroff, J. K. Kriebel, R. G. Nuzzo and G. M.
   Whitesides, *Chem. Rev.*, 2005, **105**, 1103.
- 3 S. Szunerits, C. E. Nebel and R. J. Hamers, *MRS Bulletin*, 2014, **39**, 517.
- 4(a) D. Ballutaud, N. Simon, H. Girard, E. Rzepka and B. Bouchet-Fabre, *Diamond and Related Materials*, 2006, **15**, 716; (b)
- H. Notsu, I. Yagi, T. Tatsuma, D. A. Tryk and A. Fujishima, *Journal of Electroanalytical Chemistry*, 2000, 492, 31; (c)
  H. A. Girard, N. Simon, D. Ballutaud, E. de La Rochefoucauld and A. Etcheberry, *Diamond and Related Materials*, 2007, 16, 888.
- <sup>40</sup> 5 P. Strobel, M. Riedel, J. Ristein and L. Ley, *Nature*, 2004, **430**, 439.
- 6 J. P. Lagrange, A. Deneuville and E. Gheeraert, *Diamond and Related Materials*, 1998, **7**, 1390.
- 7(a) A. Hartl, E. Schmich, J. A. Garrido, J. Hernando, S. C. R. Catharino, S. Walter, P. Feulner, A. Kromka, D. Steinmuller
- and M. Stutzmann, *Nature Materials*, 2004, 3, 736; (b) B.
  Rezek, L. Michalíková, E. Ukraintsev, A. Kromka and M.
  Kalbacova, *Sensors*, 2009, 9, 3549; (c) G.-J. Zhang, K.-S. Song, Y. Nakamura, T. Ueno, T. Funatsu, I. Ohdomari and H. Kawarada, *Langmuir*, 2006, 22, 3728; (d) L.
- Marcon, M. Wang, Y. Coffinier, F. Le Normand, O. Melnyk, R. Boukherroub and S. Szunerits, *Langmuir*, 2009, 26, 1075;
  (e) L. Marcon, C. Spriet, Y. Coffinier, E. Galopin, C. Rosnoblet, S. Szunerits, L. Héliot, P.-O. Angrand and R. Boukherroub, *Langmuir*, 2010, 26, 15065.
- 55 8 Y. Kaibara, K. Sugata, M. Tachiki, H. Umezawa and H. Kawarada, *Diamond and Related Materials*, 2003, **12**, 560.

- 9 M. Tachiki, T. Fukuda, K. Sugata, H. Seo, H. Umezawa and H. Kawarada, *Applied Surface Science*, 2000, 159–160, 578.
- S. E. Pust, S. Szunerits, R. Boukherroub and G. Wittstock,
   *Nanotechnology*, 2009, 20, 075302.
  - 11(a) N. Ebejer, M. Schnippering, A. W. Colburn, M. A. Edwards and P. R. Unwin, *Analytical Chemistry*, 2010, 82, 9141; (b) S. C. S. Lai, P. V. Dudin, J. V. Macpherson and P.
- R. Unwin, Journal of the American Chemical Society, 2011,
  133, 10744; (c) N. Ebejer, A. G. Guell, S. C. S. Lai, K. McKelvey, M. E. Snowden and P. R. Unwin, Annu. Rev. Anal. Chem., 2013, 6, 329; (d) K. McKelvey, M. A. O'Connell and P. R. Unwin, Chem. Commun., 2013, 49, 2986.
- 12 P. M. Kirkman, A. G. Guell, A. S. Cuharuc and P. R. Unwin, Journal of the American Chemical Society, 2014, 136, 36.
- 13 L. A. Hutton, J. G. Iacobini, E. Bitziou, R. B. Channon, M. E. Newton and J. V. Macpherson, *Analytical Chemistry*, 2013, 85, 7230.
- T. M. Day, P. R. Unwin and J. V. Macpherson, *Nano Letters*, 2006,
   75 7, 51.
  - 15 L. Hutton, M. E. Newton, P. R. Unwin and J. V. Macpherson, *Analytical Chemistry*, 2009, 81, 1023.
  - 16 R. Boukherroub, X. Wallart, S. Szunerits, B. Marcus, P. Bouvier and M. Mermoux, *Electrochemistry Communications*, 2005, 7, 937.
  - 17 F. Maier, M. Riedel, B. Mantel, J. Ristein and L. Ley, *Physical Review Letters*, 2000, 85, 3472.
  - 18 M. E. Snowden, A. G. Güell, S. C. S. Lai, K. McKelvey, N. Ebejer, M. A. O'Connell, A. W. Colburn and P. R. Unwin, *Analytical Chemistry*, 2012, 84, 2483.
  - 19 H. V. Patten, K. E. Meadows, L. A. Hutton, J. G. Iacobini, D. Battistel, K. McKelvey, A. W. Colburn, M. E. Newton, J. V. Macpherson and P. R. Unwin, *Angew. Chem. Int. Edit.*, 2012, 51, 7002.
- 90 20 H. V. Patten, S. C. S. Lai, J. V. Macpherson and P. R. Unwin, Analytical Chemistry, 2012, 84, 5427.
  - 21 A. G. Güell, N. Ebejer, M. E. Snowden, J. V. Macpherson and P. R. Unwin, *Journal of the American Chemical Society*, 2012, 134, 7258.
- 95 22 M. A. O'Connell, M. E. Snowden, K. McKelvey, F. Gayet, I. Shirley, D. M. Haddleton and P. R. Unwin, *Langmuir*, 2014, 30, 10011.
  - 23 R. Hoffmann, A. Kriele, H. Obloh, J. Hees, M. Wolfer, W. Smirnov, N. Yang and C. E. Nebel, *Applied Physics Letters*, 2010, 97.

100



We report the use of scanning electrochemical cell microscopy (SECCM) for the electrochemical "read-write" patterning of boron doped diamond electrodes